



U.S. UTILITY Patent Application

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PATENT DATE

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APPLICATION NO.	CONT/PRIOR	CLASS	IV	SUBCLASS	ART UNIT	EXAMINER
99/682 151		257		758	382	DR. C. L. ...

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CONTACT method for thin silicon carbide epitaxial layer and semiconductor devices formed by these methods

PTO-2000
12/89

SEARCHED INDEXED

(FACE)